BLSC9G2731XS-200

LDMOS S-band radar power transistor Rev. 1 — 22 February 2019

AMPLEON

Product data sheet

Product profile 1.

1.1 General description

200 W LDMOS power transistor for S-band radar applications in the frequency range from 2.7 GHz to 3.1 GHz.

Typical performance

Typical RF performance at T_{case} = 25 °C; t_p = 300 μ s; δ = 10 %; I_{Dq} = 200 mA; in a class-AB demo

Test signal	f	V _{DS}	P_L	G _p	η _D
	(GHz)	(V)	(W)	(dB)	(%)
pulsed RF	2.7 to 3.1	32	200	14	45

1.2 Features and benefits

- High efficiency
- Excellent ruggedness
- Designed for S-band operation
- Excellent thermal stability
- Easy power control
- Integrated dual sided ESD protection enables excellent off-state isolation
- High flexibility with respect to pulse formats
- Internally matched for ease of use
- For RoHS compliance see the product details on the Ampleon website

1.3 Applications

■ S-band radar applications in the frequency range 2.7 GHz to 3.1 GHz

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain		
2	gate	1 .	1
3	source [1]		2 3 3 sym112

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Packaç	ge			
	Name	Description Version			
BLSC9G2731XS-200	-	air cavity plastic earless flanged package; 2 leads	SOT1270-1		

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
V_{DS}	drain-source voltage	-	65	V
V_{GS}	gate-source voltage	-6	+13	V
T _{stg}	storage temperature	-65	+150	°C
Tj	junction temperature [1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability. For details refer to the online MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
Z _{th(j-c)}	transient thermal impedance from junction	T _{case} = 85 °C; P _L = 200 W		
	to case	t_p = 100 μ s; δ = 10 %	0.205	K/W
		t _p = 200 μs; δ = 10 %	0.230	K/W
		t_p = 300 μ s; δ = 10 %	0.250	K/W
		t_p = 500 μ s; δ = 10 %	0.278	K/W
		$t_p = 1 \text{ ms}; \delta = 10 \%$	0.322	K/W
		t _p = 100 μs; δ = 20 %	0.234	K/W

6. Characteristics

Table 6. DC characteristics

 T_i = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1.8 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 20 \text{ V}; I_D = 180 \text{ mA}$	1.5	2.0	2.5	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 32 V	-	-	2.8	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 20 \text{ V}$	-	36	-	Α
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	280	nA
g _{fs}	forward transconductance	V_{DS} = 20 V; I_{D} = 180 mA	-	1.7	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 6.3 \text{ A}$	-	0.079	-	Ω

Table 7. RF characteristics

Test signal: pulsed RF; t_p = 300 μ s; δ = 10 %; RF performance at V_{DS} = 32 V; I_{Dq} = 200 mA; T_{case} = 25 °C; unless otherwise specified, in a class-AB production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P _L = 200 W	13	14	-	dB
η_{D}	drain efficiency	P _L = 200 W	41	45	-	%
RLin	input return loss	P _L = 200 W	-	-10	-	dB
P _{droop(pulse)}	pulse droop power	P _L = 200 W	-	0.0	0.3	dB
t _r	rise time	P _L = 200 W	-	6	50	ns
t _f	fall time	P _L = 200 W	-	6	50	ns
P _{L(2dB)}	output power at 2 dB gain compression		-	200	-	W

7. Test information

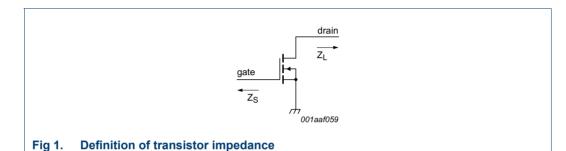
7.1 Ruggedness in class-AB operation

The BLSC9G2731XS-200 is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 32 V; I_{Dq} = 200 mA; P_L = 200 W; t_p = 300 μ s; δ = 10 %.

7.2 Impedance information

Table 8. Typical impedance

f	Z _S	Z _L
(GHz)	(Ω)	(Ω)
2.7	2.2 – j5.3	1.8 – j5.0
2.8	2.0 – j4.2	2.0 – j4.1
2.9	1.9 – j3.1	2.4 – j3.2
	2.0 – j2.0	3.2 – j2.4
3.1	2.1 – j0.9	4.6 – j2.0



7.3 Test circuit information

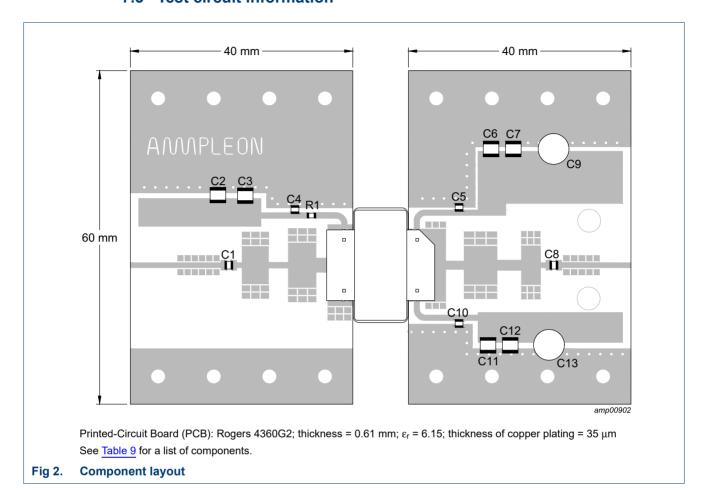
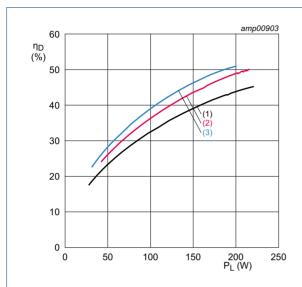


Table 9. List of components For test circuit see Figure 2.

Component	Description	Value	Remarks
C1, C8	multilayer ceramic chip capacitor	15 pF	ATC 800A
C4, C5, C10	multilayer ceramic chip capacitor	15 pF	ATC 100A
C3, C6, C11	multilayer ceramic chip capacitor	1 nF	ATC 100B
C2, C7, C12	multilayer ceramic chip capacitor	10 μF	Murata: GRM55DR61H106KA88L
C9, C13	electrolytic capacitor	100 μF, 63 V	
R1	resistor	5 Ω	SMD 0603

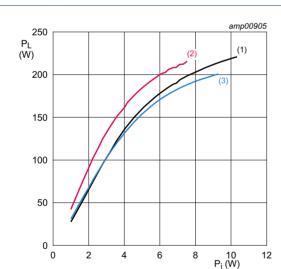
7.4 Graphical data



 V_{DS} = 32 V; I_{Dq} = 200 mA; t_p = 300 μ s; δ = 10 %.

- (1) f = 2700 MHz
- (2) f = 2900 MHz
- (3) f = 3100 MHz

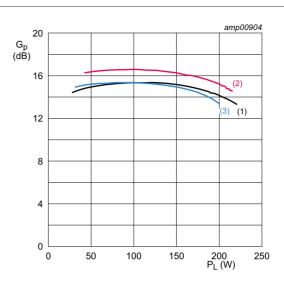
Fig 3. Drain efficiency as a function of output power; typical values



 V_{DS} = 32 V; I_{Dq} = 200 mA; t_p = 300 μ s; δ = 10 %.

- (1) f = 2700 MHz
- (2) f = 2900 MHz
- (3) f = 3100 MHz

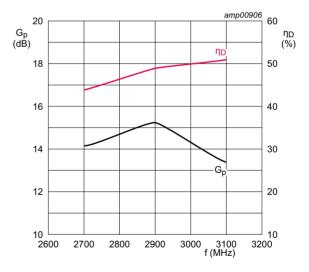
Fig 5. Output power as a function of input power; typical values



 V_{DS} = 32 V; I_{Dq} = 200 mA; t_p = 300 μ s; δ = 10 %.

- (1) f = 2700 MHz
- (2) f = 2900 MHz
- (3) f = 3100 MHz

Fig 4. Power gain as a function of output power; typical values



 V_{DS} = 32 V; I_{Dq} = 200 mA; P_L = 200 W; t_p = 300 μs ; δ = 10 %.

Fig 6. Power gain and drain efficiency as function of frequency; typical values

8. Package outline

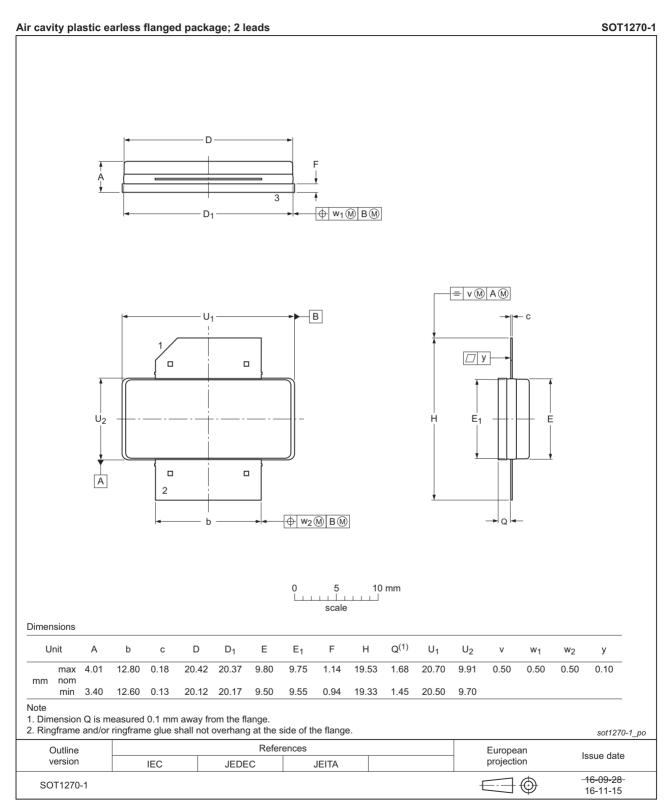


Fig 7. Package outline SOT1270-1

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 10. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

- [1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V.
- [2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

10. Abbreviations

Table 11. Abbreviations

Acronym	Description
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
RoHS	Restriction of Hazardous Substances
S-band	Short wave Band
SMD	Surface Mounted Device
VSWR	Voltage Standing Wave Ratio

11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLSC9G2731XS-200 v.1	20190222	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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LDMOS S-band radar power transistor

14. Contents

1	Product profile	. 1
1.1	General description	. 1
1.2	Features and benefits	
1.3	Applications	. 1
2	Pinning information	. 2
3	Ordering information	. 2
4	Limiting values	. 2
5	Thermal characteristics	. 2
6	Characteristics	. 3
7	Test information	. 3
7.1	Ruggedness in class-AB operation	. 3
7.2	Impedance information	
7.3	Test circuit information	
7.4	Graphical data	. 6
8	Package outline	. 7
9	Handling information	. 8
10	Abbreviations	
11	Revision history	. 8
12	Legal information	. 9
12.1	Data sheet status	. 9
12.2	Definitions	. 9
12.3	Disclaimers	. 9
12.4	Trademarks	10
13	Contact information	10
14	Contents	11

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